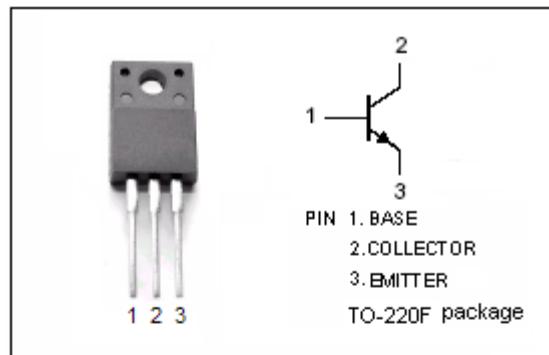


## isc Silicon NPN Power Transistor

2SC4550

**DESCRIPTION**

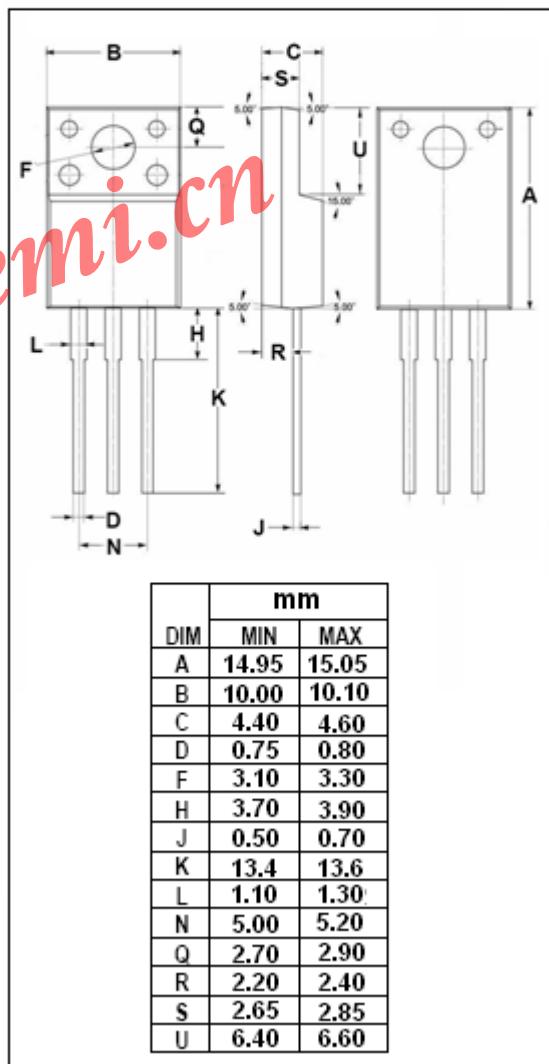
- Collector-Emitter Sustaining Voltage-  
:  $V_{CEO(SUS)} = 60V(\text{Min})$
- High DC Current Gain-  
:  $h_{FE} = 100(\text{Min}) @ (V_{CE} = 2V, I_C = 1.5A)$
- Low Saturation Voltage-  
:  $V_{CE(sat)} = 0.3V(\text{Max}) @ (I_C = 4A, I_B = 0.2A)$

**APPLICATIONS**

- Designed for use as a driver in DC/DC converters and actuators.

**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	100	V
$V_{CEO}$	Collector-Emitter Voltage	60	V
$V_{EBO}$	Emitter-Base Voltage	7.0	V
$I_C$	Collector Current-Continuous	7.0	A
$I_{CM}$	Collector Current-Pulse	14	A
$I_B$	Base Current-Continuous	3.5	A
$P_T$	Total Power Dissipation @ $T_c=25^\circ\text{C}$	30	W
	Total Power Dissipation @ $T_a=25^\circ\text{C}$	2.0	
$T_J$	Junction Temperature	150	°C
$T_{stg}$	Storage Temperature	-55~150	°C



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## ELECTRICAL CHARACTERISTICS

 $T_j=25^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{CEO(\text{SUS})}$	Collector-Emitter Sustaining Voltage	$I_C = 4.0\text{A} ; I_B = 0.4\text{A}, L = 1\text{mH}$	60			V
$V_{CEX(\text{SUS})}$	Collector-Emitter Sustaining Voltage	$I_C = 4.0\text{A} ; I_{B1} = -I_{B2} = 0.4\text{A}, V_{BE(\text{OFF})} = -1.5\text{V}, L = 180\ \mu\text{H, clamped}$	60			V
$V_{CE(\text{sat})-1}$	Collector-Emitter Saturation Voltage	$I_C = 4\text{A}; I_B = 0.2\text{A}$			0.3	V
$V_{CE(\text{sat})-2}$	Collector-Emitter Saturation Voltage	$I_C = 6\text{A}; I_B = 0.3\text{A}$			0.5	V
$V_{BE(\text{sat})-1}$	Base-Emitter Saturation Voltage	$I_C = 4\text{A}; I_B = 0.2\text{A}$			1.2	V
$V_{BE(\text{sat})-2}$	Base-Emitter Saturation Voltage	$I_C = 6\text{A}; I_B = 0.3\text{A}$			1.5	V
$I_{CBO}$	Collector Cutoff Current	$V_{CB} = 60\text{V} ; I_E = 0$			10	$\mu\text{A}$
$I_{CER}$	Collector Cutoff Current	$V_{CE} = 60\text{V} ; R_{BE} = 50\ \Omega, T_a = 125^\circ\text{C}$			1.0	mA
$I_{CEX}$	Collector Cutoff Current	$V_{CE} = 60\text{V}; V_{BE(\text{off})} = -1.5\text{V}$ $V_{CE} = 60\text{V}; V_{BE(\text{off})} = 1.5\text{V}, T_a = 125^\circ\text{C}$			10 1.0	$\mu\text{A}$ mA
$I_{EBO}$	Emitter Cutoff Current	$V_{EB} = 5\text{V}; I_C = 0$			10	$\mu\text{A}$
$h_{FE-1}$	DC Current Gain	$I_C = 0.7\text{A} ; V_{CE} = 2\text{V}$	100			
$h_{FE-2}$	DC Current Gain	$I_C = 1.5\text{A} ; V_{CE} = 2\text{V}$	100		400	
$h_{FE-3}$	DC Current Gain	$I_C = 4.0\text{A} ; V_{CE} = 2\text{V}$	60			
$C_{OB}$	Output Capacitance	$I_E = 0 ; V_{CB} = 10\text{V}; f = 1.0\text{MHz}$		100		pF
$f_T$	Current-Gain—Bandwidth Product	$I_C = 1\text{A} ; V_{CE} = 10\text{V}$		150		MHz

Switching times

$t_{on}$	Turn-on Time	$I_C = 4.0\text{A}, R_L = 12.5\ \Omega, I_{B1} = -I_{B2} = 0.2\text{A}, V_{CC} \approx 50\text{V}$			0.3	$\mu\text{s}$
$t_{stg}$	Storage Time				1.5	$\mu\text{s}$
$t_f$	Fall Time				0.3	$\mu\text{s}$

◆  $h_{FE-2}$  Classifications

M	L	K
100-200	150-300	200-400